

ISP815X,ISP825X,ISP845X3,2,1
ISP815,ISP825,ISP845-3,-2,-1



ISOCOM

COMPONENTS

LOW INPUT CURRENT PHOTODARLINGTON OPTICALLY COUPLED ISOLATORS



APPROVALS

- UL recognised, File No. E91231
- 'X' SPECIFICATION APPROVALS
 - VDE 0884 in 3 available lead form : -
 - STD
 - G form
 - SMD approved to CECC 00802
- Certified to EN60950 by the following Test Bodies :-
 - Nemko - Certificate No. P01102465
 - Fimko - Certificate No. FI18162
 - Semko - Reference No. 0202041/01-25
 - Demko - Certificate No. 311161-01
- BSI approved - Certificate No. 8001

DESCRIPTION

The ISP815-3,-2,-1, ISP825-3,-2,-1, ISP845-3,-2,-1 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photodarlington transistors in space efficient dual in line plastic packages.

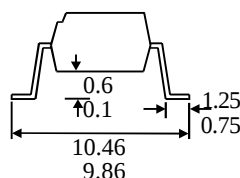
FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape & reel - add SMT&R after part no.
- Low input current 0.25mA I_F
- High Current Transfer Ratio (200% min)
- High Isolation Voltage (5.3kV_{RMS})
- High BV_{CEO} (70V min)
- All electrical parameters 100% tested
- Custom electrical selections available

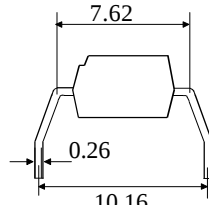
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

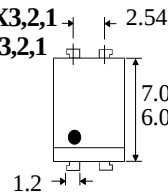
OPTION SM SURFACE MOUNT



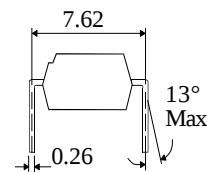
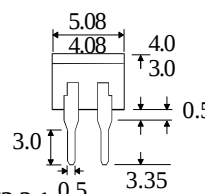
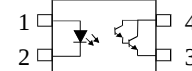
OPTION G



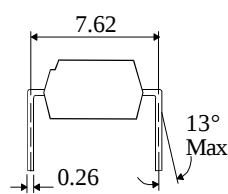
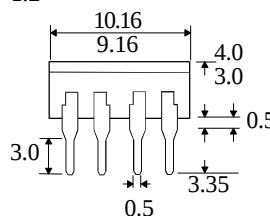
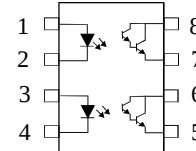
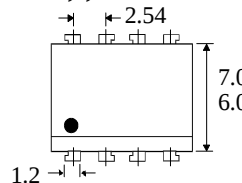
ISP815X3,2,1 ISP815-3,2,1



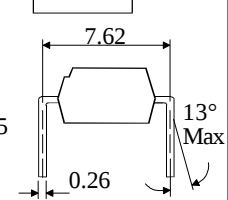
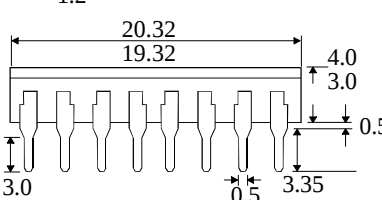
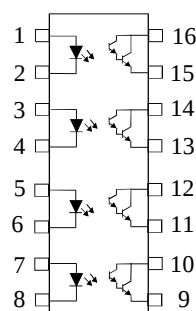
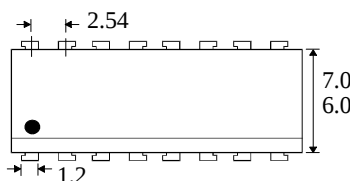
Dimensions in mm



ISP825X3,2,1 ISP825-3,2,1



ISP845X3,2,1 ISP845-3,2,1



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature _____ -55°C to + 125°C
Operating Temperature _____ -30°C to + 100°C
Lead Soldering Temperature
(1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 50mA
Reverse Voltage _____ 6V
Power Dissipation _____ 70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO} _____ 70V
Emitter-collector Voltage BV_{ECO} _____ 6V
Power Dissipation _____ 150mW

POWER DISSIPATION

Total Power Dissipation _____ 200mW
(derate linearly 2.67mW/°C above 25°C)

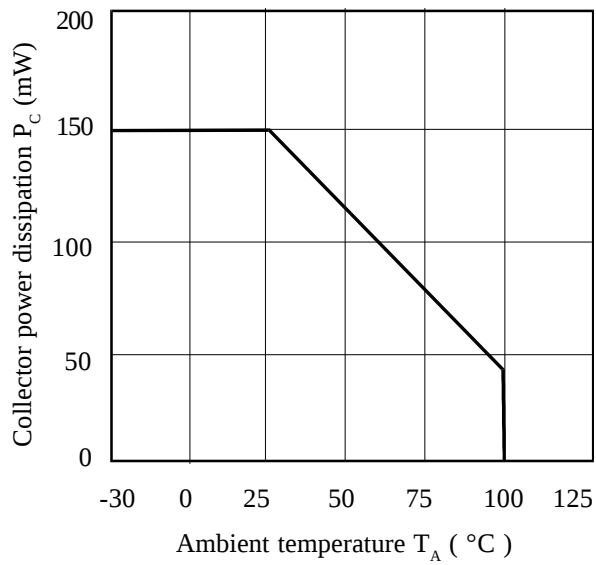
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	$I_F = 20\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 4\text{V}$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	70			V	$I_C = 1\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO})			100	nA	$V_{CE} = 20\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2) ISP815-3, ISP825-3, ISP845-3	200			%	0.25mA I_F , 1.0V V_{CE}
		400			%	0.5mA I_F , 1.0V V_{CE}
		800			%	1.0mA I_F , 1.0V V_{CE}
	ISP815-2, ISP825-2, ISP845-2	400			%	0.5mA I_F , 1.0V V_{CE}
		800			%	1.0mA I_F , 1.0V V_{CE}
	ISP815-1, ISP825-1, ISP845-1	800			%	1.0mA I_F , 1.0V V_{CE}
	Collector-emitter Saturation Voltage -3			1.0	V	0.25mA I_F , 0.5mA I_C
	-2			1.0	V	0.5mA I_F , 2mA I_C
	-1			1.0	V	1.0mA I_F , 8mA I_C
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Output Rise Time tr		60	300	μs	$V_{CE} = 2\text{V}$,
	Output Fall Time tf		53	250	μs	$I_C = 10\text{mA}$, $R_L = 100\Omega$

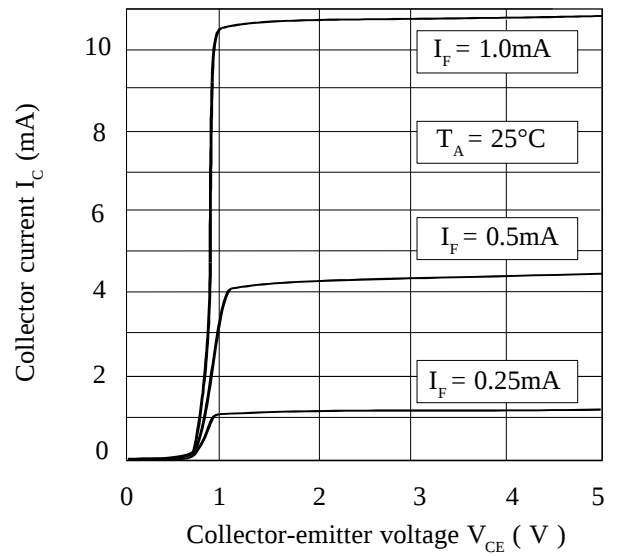
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

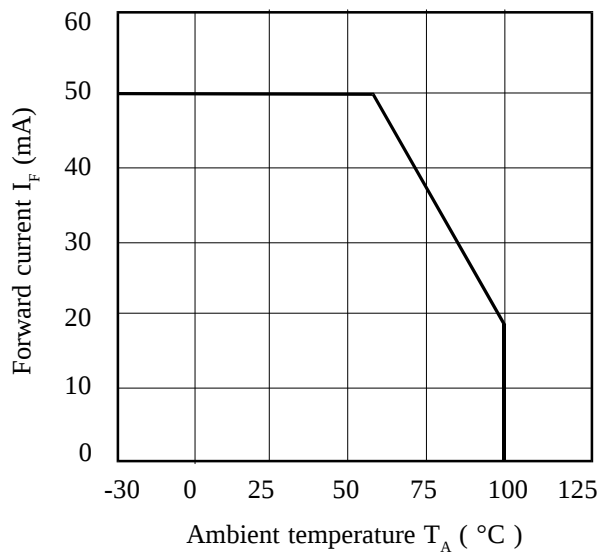
Collector Power Dissipation vs. Ambient Temperature



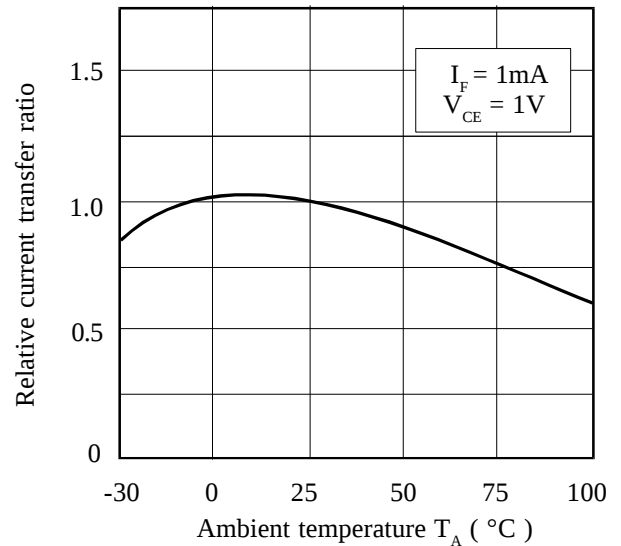
Collector Current vs. Collector-emitter Voltage



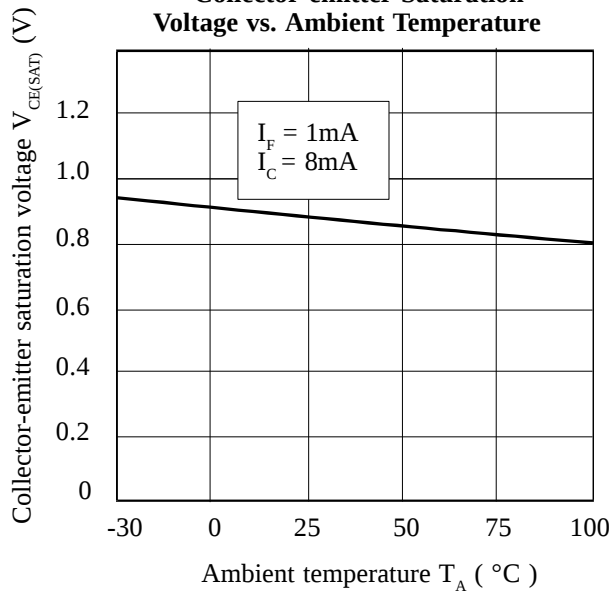
Forward Current vs. Ambient Temperature



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current

